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Kind regards,

Team Nexperia



# BAT54T

# Single Schottky barrier diode Rev. 01 — 14 December 2009

Product data sheet

#### **Product profile** 1.

### 1.1 General description

Single planar Schottky barrier diode with an integrated guard ring for stress protection, encapsulated in a SOT416 (SC-75) ultra small Surface-Mounted Device (SMD) plastic package.

#### 1.2 Features

- Low forward voltage: max. 400 mV
- Low capacitance: max. 10 pF
- Ultra small SMD plastic package
- AEC-Q101 qualified

### 1.3 Applications

- Ultra high-speed switching
- Voltage clamping
- Protection circuits
- Blocking diode

#### 1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>F</sub>	forward current		-	-	200	mA
$V_R$	reverse voltage		-	-	30	V
V <sub>F</sub>	forward voltage	$I_F = 10 \text{ mA}$	[1] _	-	400	mV

[1] Pulse test:  $t_p \leq 300~\mu s;~\delta \leq 0.02.$ 



## Single Schottky barrier diode

# 2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Graphic symbol
1	anode		
2	not connected	3	3
3	cathode	1 2	1 2 n.c. 006aaa436

# 3. Ordering information

Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
BAT54T	SC-75	plastic surface-mounted package; 3 leads	SOT416		

# 4. Marking

Table 4. Marking codes

Type number	Marking code
BAT54T	ZW

# 5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_R$	reverse voltage		-	30	V
I <sub>F</sub>	forward current		-	200	mA
I <sub>FRM</sub>	repetitive peak forward current	$t_p \leq 1 \text{ s; } \delta \leq 0.5$	-	300	mA
I <sub>FSM</sub>	non-repetitive peak forward current	square wave			
		t <sub>p</sub> = 100 μs	-	4	Α
		$t_p = 1 \text{ ms}$	-	2	Α
		t <sub>p</sub> = 10 ms	-	1	Α
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25  ^{\circ}C$	<u>[1]</u> -	150	mW
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		<b>–55</b>	+150	°C
T <sub>stg</sub>	storage temperature		-65	+150	°C

<sup>[1]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

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### Single Schottky barrier diode

# 6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	<u>[1]</u> -	-	833	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point		[2] -	-	350	K/W

<sup>[1]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

## 7. Characteristics

Table 7. Characteristics

 $T_{amb} = 25 \, ^{\circ}\text{C}$  unless otherwise specified.

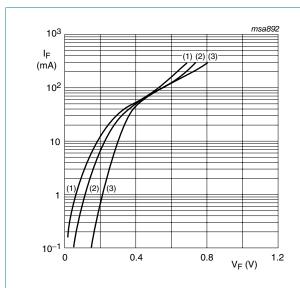
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{F}$	forward voltage		<u>[1]</u>			
		$I_F = 0.1 \text{ mA}$	-	-	240	mV
		I <sub>F</sub> = 1 mA	-	-	320	mV
		I <sub>F</sub> = 10 mA	-	-	400	mV
		$I_F = 30 \text{ mA}$	-	-	500	mV
		I <sub>F</sub> = 100 mA	-	-	800	mV
$I_R$	reverse current	V <sub>R</sub> = 25 V	-	-	2	μΑ
t <sub>rr</sub>	reverse recovery time		[2] _	-	5	ns
$C_{d}$	diode capacitance	$V_R = 1 V$ ; $f = 1 MHz$	-	-	10	pF

<sup>[1]</sup> Pulse test:  $t_p \leq 300~\mu s;~\delta \leq 0.02.$ 

<sup>[2]</sup> Soldering point of cathode tab.

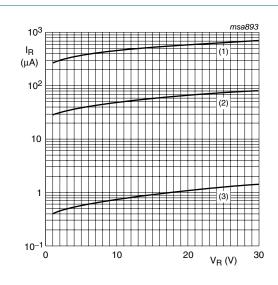
<sup>[2]</sup> When switched from  $I_F$  = 10 mA to  $I_R$  = 10 mA;  $R_L$  = 100  $\Omega;$  measured at  $I_R$  = 1 mA.

## Single Schottky barrier diode



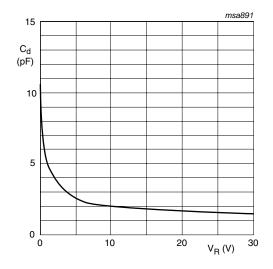
- (1)  $T_{amb} = 125 \, ^{\circ}C$
- (2)  $T_{amb} = 85 \, ^{\circ}C$
- (3)  $T_{amb} = 25 \, ^{\circ}C$

Fig 1. Forward current as a function of forward voltage; typical values



- (1)  $T_{amb} = 125 \, ^{\circ}C$
- (2)  $T_{amb} = 85 \, ^{\circ}C$
- (3)  $T_{amb} = 25 \, ^{\circ}C$

Fig 2. Reverse current as a function of reverse voltage; typical values

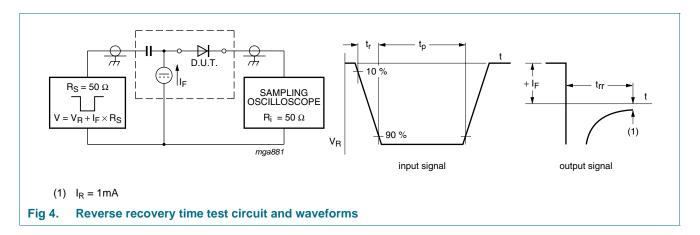


 $f = 1 \text{ MHz}; T_{amb} = 25 \text{ }^{\circ}\text{C}$ 

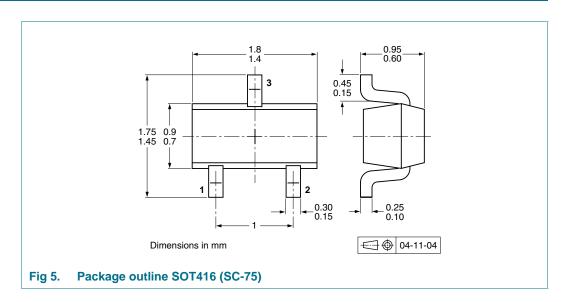
Fig 3. Diode capacitance as a function of reverse voltage; typical values

Single Schottky barrier diode

# 8. Test information



# 9. Package outline



## Single Schottky barrier diode

# 10. Packing information

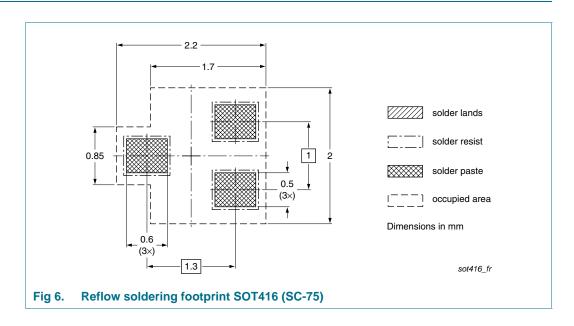
Table 8. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing quantity	
			3000	10000
BAT54T	SOT416	4 mm pitch, 8 mm tape and reel	-115	-135

<sup>[1]</sup> For further information and the availability of packing methods, see Section 14.

# 11. Soldering



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Single Schottky barrier diode

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# 12. Revision history

#### Table 9. **Revision history**

Product data sheet

Document ID	Release date	Data sheet status	Change notice	Supersedes
BAT54T_1	20091214	Product data sheet	-	-

#### Single Schottky barrier diode

# 13. Legal information

#### 13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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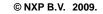
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## Single Schottky barrier diode

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